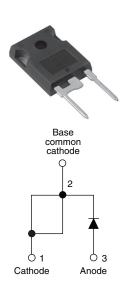


Vishay High Power Products

HEXFRED® Ultrafast Soft Recovery Diode, 30 A



TO-247AC modified

PRODUCT SUMMARY					
V_{R}	1200 V				
V _F at 30 A at 25 °C	4.1 V				
I _{F(AV)}	30 A				
t _{rr} (typical)	47 ns				
T _J (maximum)	150 °C				
Q _{rr} (typical)	120 nC				
dl _{(rec)M} /dt (typical) at 125 °C	240 A/μs				
I _{RRM} (typical)	4.7 A				

FEATURES

- · Ultrafast recovery
- · Ultrasoft recovery
- Very low I_{RRM}
- Very low Q_{rr}
- Guaranteed avalanche
- Specified at operating conditions
- · Lead (Pb)-free
- · Designed and qualified for industrial level

BENEFITS

- · Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- · Higher frequency operation
- · Reduced snubbing
- · Reduced parts count

DESCRIPTION

HFA30PB120 is a state of the art center tap ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 1200 V and 30 A continuous current, the HFA30PB120 is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I_{RRM}) and does not exhibit any tendency to "snap-off" during the t_{b} portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA30PB120 is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Cathode to anode voltage	V _R		1200	V	
Maximum continuous forward current	I _F	T _C = 100 °C	30		
Single pulse forward current	I _{FSM}		120	Α	
Maximum repetitive forward current	I _{FRM}		90		
Maximum naviar dissination	P _D	T _C = 25 °C	350	W	
Maximum power dissipation		T _C = 100 °C	140		
Operating junction and storage temperature range	T _J , T _{Stg}		- 55 to + 150	°C	

^{*} Pb containing terminations are not RoHS compliant, exemptions may apply

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HFA30PB120PbF

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ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V _{BR}	Ι _R = 100 μΑ		1200	-	-	
	V _{FM}	I _F = 30 A	See fig. 1	-	2.4	4.1	V
Maximum forward voltage		I _F = 60 A		-	3.1	5.7	
		I _F = 30 A, T _J = 125 °C		-	2.3	4.0	
Maximum reverse		$V_R = V_R$ rated	See fig. 2	-	1.3	40	
leakage current	I _{RM}	T_J = 125 °C, V_R = 0.8 x V_R rated	See lig. 2	-	1.1	4000	μΑ
Junction capacitance	C _T	V _R = 200 V	See fig. 3	=	50	75	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body		=	8.0	=	nΗ

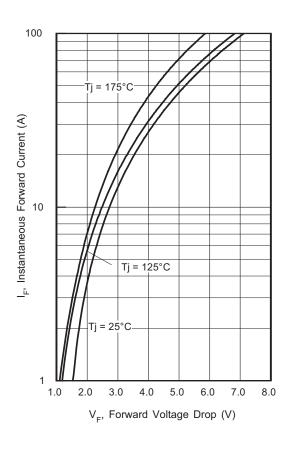
DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
	t _{rr}	$I_F = 1.0 \text{ A}, dI_F/dt = 200 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	47	-	
Reverse recovery time See fig. 5, 10	t _{rr1}	T _J = 25 °C		-	110	170	ns
000 lig. 0, 10	t _{rr2}	T _J = 125 °C		-	170	260]
Peak recovery current See fig. 6	I _{RRM1}	T _J = 25 °C	$I_F = 30 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 200 \text{ V}$	-	10	15	А
	I _{RRM2}	T _J = 125 °C		-	16	24	
Reverse recovery charge	Q _{rr1}	T _J = 25 °C		-	650	980	nC
See fig. 7	Q _{rr2}	T _J = 125 °C		-	1540	2310	110
Peak rate of fall of recovery current during t _b See fig. 8	dI _{(rec)M} /dt1	T _J = 25 °C		-	270	-	- A/μs
	dI _{(rec)M} /dt2	T _J = 125 °C		-	240	-	Ανμδ

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Lead temperature	T _{lead}	0.063" from case (1.6 mm) for 10 s	-	-	300	°C
Thermal resistance, junction to case	R _{thJC}		-	-	0.36	
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	80	°C/W
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.50	-	
Maight			-	2.0	-	g
Weight			-	0.07	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style TO-247AC modified (JEDEC)	HFA30PB120			

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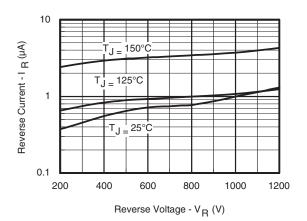


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

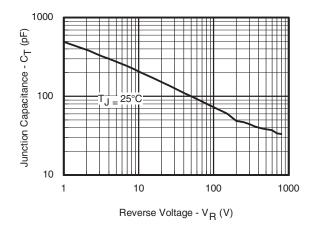


Fig. 1 - Typical Forward Voltage Drop vs. Instantaneous Forward Current

Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

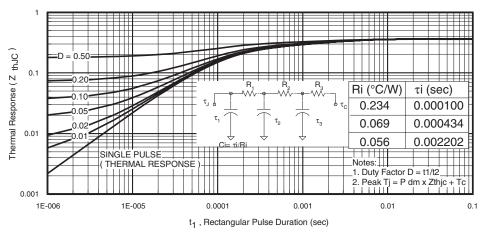


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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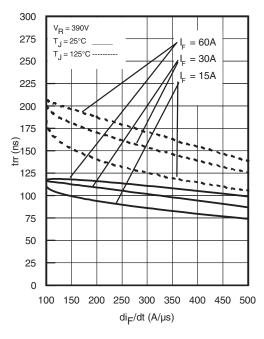


Fig. 5 - Typical Reverse Recovery Time vs. dI_F/dt (Per Leg)

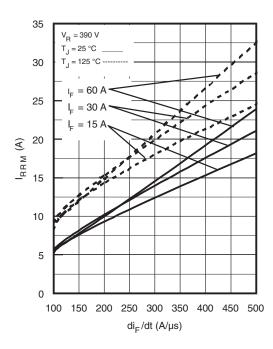


Fig. 6 - Typical Recovery Current vs. dI_F/dt (Per Leg)

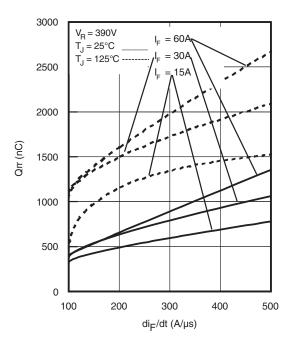


Fig. 7 - Typical Stored Charge vs. dl_F/dt (Per Leg)

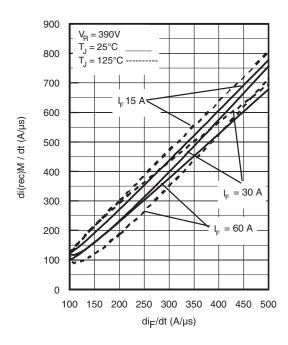


Fig. 8 - Typical $dI_{(rec)M}/dt$ vs. dI_F/dt (Per Leg)

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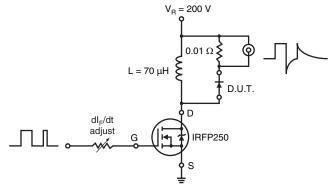
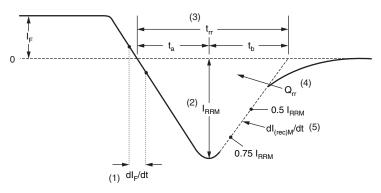


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dI_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) Q_{rr} area under curve defined by t_{rr} and I_{RBM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) dI_{(rec)M}/dt - peak rate of change of current during t_h portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions

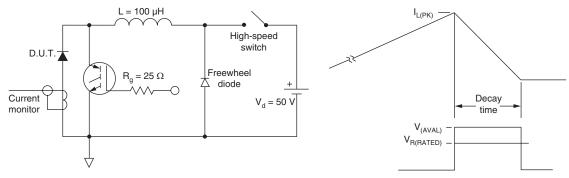


Fig. 11 - Avalanche Test Circuit and Waveforms

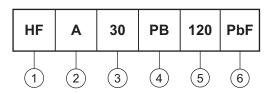
HFA30PB120PbF

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ORDERING INFORMATION TABLE

Device code



1 - HEXFRED® family

Process designator: A = Electron irradiated

B = Platinum diffused

3 - Current rating (30 = 30 A)

4 - Package outline (PB = TO-247, 2 pins)

5 - Voltage rating (120 = 1200 V)

- • None = Standard production

• PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS				
Dimensions http://www.vishay.com/doc?95253				
Part marking information	http://www.vishay.com/doc?95255			
SPICE model	http://www.vishay.com/doc?95358			



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